

#### AUTOMOTIVE GRADE

PD - 97544

## AUIRFR4105Z AUIRFU4105Z

HEXFET<sup>®</sup> Power MOSFET

#### Features

- Advanced Process Technology
- Ultra Low On-Resistance
- 175°C Operating Temperature
- Fast Switching
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified \*

#### Description

Specifically designed for Automotive applications, this HEXFET<sup>®</sup> Power MOSFET utilizes the latest processing techniques to achieve extremely low onresistance per silicon area. Additional features of this design are a 175°C junction operating temperature, fast switching speed and improved repetitive avalanche rating. These features combine to make this design an extremely efficient and reliable device for use in Automotive applications and a wide variety of other applications.

$\leq$ [	V(BR)DSS	55 V
	R <sub>DS(on)</sub> max.	<b>24.5m</b> Ω
∕s	I <sub>D</sub>	30A

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G D-Pak AUIRFR4105Z	I-Pak G AUIRFU4105Z	

G	D	S
Gate	Drain	Source

#### **Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature ( $T_A$ ) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
I <sub>D</sub> @ T <sub>C</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	30	
I <sub>D</sub> @ T <sub>C</sub> = 100°	C Continuous Drain Current, V <sub>GS</sub> @ 10V	21	A
I <sub>DM</sub>	Pulsed Drain Current ①	120	7
$P_{D} @ T_{C} = 25^{\circ}C$	Power Dissipation	48	W
	Linear Derating Factor	0.32	W/°C
V <sub>GS</sub>	Gate-to-Source Voltage	± 20	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Thermally Limited) 2	29	mJ
E <sub>AS</sub> (tested)	Single Pulse Avalanche Energy Tested Value 6	46	7
I <sub>AR</sub>	Avalanche Current ①	See Fig.12a, 12b, 15, 16	A
E <sub>AR</sub>	Repetitive Avalanche Energy (5)		mJ
TJ	Operating Junction and	-55 to + 175	
T <sub>STG</sub>	Storage Temperature Range		°C
	Soldering Temperature, for 10 seconds (1.6mm from case)	300	7
	Mounting Torque, 6-32 or M3 screw	10 lbf∙in (1.1N∙m)	

	Parameter	Тур.	Max.	Units
R <sub>0JC</sub>	Junction-to-Case ®		3.12	
R <sub>0JA</sub>	Junction-to-Ambient (PCB mount) ⑦		50	°C/W
$R_{\theta JA}$	Junction-to-Ambient		110	

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\*Qualification standards can be found at http://www.irf.com/

	Parameter	Min.	Тур.	Max.	Units	Conditions	
V <sub>(BR)DSS</sub>	Drain-to-Source Breakdown Voltage	55			V	$V_{GS} = 0V, I_{D} = 250\mu A$	
$\Delta V_{(BR)DSS} / \Delta T$	Breakdown Voltage Temp. Coefficient		0.053		V/°C	Reference to 25°C, I <sub>D</sub> = 1mA	
R <sub>DS(on)</sub>	Static Drain-to-Source On-Resistance		19	24.5	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 18A ③	
V <sub>GS(th)</sub>	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
gfs	Forward Transconductance	16			S	V <sub>DS</sub> = 15V, I <sub>D</sub> = 18A	
IDSS	Drain-to-Source Leakage Current			20	μA	$V_{DS} = 55V, V_{GS} = 0V$	
				250	1	$V_{DS} = 55V, V_{GS} = 0V, T_{J} = 125^{\circ}C$	
I <sub>GSS</sub>	Gate-to-Source Forward Leakage			200	nA	$V_{GS} = 20V$	
	Gate-to-Source Reverse Leakage			-200	1	V <sub>GS</sub> = -20V	
Dynamic	Electrical Characteristics @ T <sub>J</sub> =	= 25°C	(unle	ss oth	herwis	e specified)	
	Parameter	Min.	Тур.	Max.	Units	Conditions	
Qg	Total Gate Charge		18	27		I <sub>D</sub> = 18A	
Q <sub>gs</sub>	Gate-to-Source Charge		5.3		nC	$V_{DS} = 44V$	
Q <sub>gd</sub>	Gate-to-Drain ("Miller") Charge		7.0		1	V <sub>GS</sub> = 10V ③	
t <sub>d(on)</sub>	Turn-On Delay Time		10			$V_{DD} = 28V$	
t <sub>r</sub>	Rise Time		40		1	I <sub>D</sub> = 18A	
t <sub>d(off)</sub>	Turn-Off Delay Time		26		ns	$R_{G} = 24.5 \Omega$	
t <sub>f</sub>	Fall Time		24		1	V <sub>GS</sub> = 10V ③	
L <sub>D</sub>	Internal Drain Inductance		4.5			Between lead,	
					nH	6mm (0.25in.)	
L <sub>s</sub>	Internal Source Inductance		7.5		1	from package	
						and center of die contact	
C <sub>iss</sub>	Input Capacitance		740			$V_{GS} = 0V$	
C <sub>oss</sub>	Output Capacitance		140		]	$V_{DS} = 25V$	
C <sub>rss</sub>	Reverse Transfer Capacitance		74		pF	f = 1.0MHz	
C <sub>oss</sub>	Output Capacitance		450			$V_{GS} = 0V, V_{DS} = 1.0V, f = 1.0MH$	
C <sub>oss</sub>	Output Capacitance		110		]	$V_{GS} = 0V, V_{DS} = 44V, f = 1.0MHz$	
C <sub>oss</sub> eff.	Effective Output Capacitance		180		]	$V_{GS} = 0V, V_{DS} = 0V \text{ to } 44V $	
<b>Diode Cl</b>	haracteristics						
	Deremeter	Min	Tun	Max	Linite	Conditiono	

#### Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
I <sub>S</sub>	Continuous Source Current			30		MOSFET symbol
	(Body Diode)				А	showing the
I <sub>SM</sub>	Pulsed Source Current			120		integral reverse
	(Body Diode) ①					p-n junction diode.
V <sub>SD</sub>	Diode Forward Voltage			1.3	V	$T_J$ = 25°C, $I_S$ = 18A, $V_{GS}$ = 0V $③$
t <sub>rr</sub>	Reverse Recovery Time		19	29		$T_{J} = 25^{\circ}C, I_{F} = 18A, V_{DD} = 28V$
Q <sub>rr</sub>	Reverse Recovery Charge		14	21	nC	di/dt = 100A/µs ③
t <sub>on</sub>	Forward Turn-On Time	Intrinsio	turn-or	time is	negligib	le (turn-on is dominated by LS+LD)

		Automotive			
		(per AEC-Q101) <sup>††</sup>			
Qualification Level		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.			
		D-PAK	MSL1		
woisture	Sensitivity Level	I-PAK	MSL1		
	Machine Model	Class M2 (200V)			
		AEC-Q101-002			
	Human Body Model	Class H1A (500V)			
ESD			AEC-Q101-001		
	Charged Device	Class C5 (1125V)			
	Model		AEC-Q101-005		
RoHS Compliant		Yes			

#### Qualification Information<sup>†</sup>

† Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

**††** Exceptions to AEC-Q101 requirements are noted in the qualification report.

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Fig 2. Typical Output Characteristics









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Fig 10. Normalized On-Resistance Vs. Temperature



Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

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Fig 12a. Unclamped Inductive Test Circuit



Fig 12b. Unclamped Inductive Waveforms



Fig 13a. Basic Gate Charge Waveform



Fig 13b. Gate Charge Test Circuit www.irf.com



Fig 12c. Maximum Avalanche Energy Vs. Drain Current



Fig 14. Threshold Voltage Vs. Temperature

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Fig 15. Typical Avalanche Current Vs.Pulsewidth





#### Notes on Repetitive Avalanche Curves , Figures 15, 16: (For further info, see AN-1005 at www.irf.com)

- Avalanche failures assumption: Purely a thermal phenomenon and failure occurs at a temperature far in excess of T<sub>jmax</sub>. This is validated for every part type.
- Safe operation in Avalanche is allowed as long asT<sub>jmax</sub> is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 12a, 12b.
- P<sub>D</sub> (ave) = Average power dissipation per single avalanche pulse.
- 5. BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6.  $I_{av}$  = Allowable avalanche current.
- 7.  $\Delta$ T = Allowable rise in junction temperature, not to exceed T<sub>imax</sub> (assumed as 25°C in Figure 15, 16).
  - $t_{av}$  = Average time in avalanche.
  - D = Duty cycle in avalanche =  $t_{av} \cdot f$

 $Z_{thJC}(D, t_{av}) = Transient thermal resistance, see figure 11)$ 

$$\begin{split} P_{D~(ave)} &= 1/2~(~1.3{\cdot}BV{\cdot}I_{av}) = {\bigtriangleup}T/~Z_{thJC}\\ I_{av} &= 2{\bigtriangleup}T/~[1.3{\cdot}BV{\cdot}Z_{th}]\\ E_{AS~(AR)} &= P_{D~(ave)}{\cdot}t_{av} \end{split}$$

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Fig 18b. Switching Time Waveforms

### D-Pak (TO-252AA) Package Outline

Dimensions are shown in millimeters (inches)



### D-Pak Part Marking Information



Note: For the most current drawing please refer to IR website at <u>http://www.irf.com/package/</u> 10 www.irf.com

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#### I-Pak (TO-251AA) Package Outline

Dimensions are shown in millimeters (inches)



NOTES: 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994

- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- $\triangle$  dimension d & e do not include Mold Flash. Mold Flash shall not exceed .005 [0.13] per side. These dimensions are measured at the outwost extremes of the plastic body.
- A- THERMAL PAD CONTOUR OPTION WITHIN DIMENSION 64, L2, E1 & D1.
- A- LEAD DIMENSION UNCONTROLLED IN L3.
- DIMENSION 61, 63 & c1 APPLY TO BASE METAL ONLY.
- 7.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-251AA (Date 06/02).
- 8.- CONTROLLING DIMENSION ; INCHES.

S	DIMENSIONS				N
M B O L	MILLIM	MILLIMETERS INCHES		HES	O T E S
L	MIN.	MAX.	MIN.	MAX.	E S
Α	2.18	2,39	.086	.094	
A1	0.89	1.14	.035	.045	
b	0.64	0.89	.025	.035	
ь1	0.65	0.79	.025	.031	6
b2	0.76	1,14	.030	.045	
bЗ	0.76	1.04	.030	.041	6
Ь4	4,95	5,46	.195	.215	4
с	0.45	0.61	.018	.024	
c1	0.41	0,56	.016	.022	6
c2	0.46	0.89	.018	.035	
D	5.97	6.22	.235	.245	3
D1	5.21	-	.205	-	4
Ε	6,35	6.73	.250	.265	3
E1	4,32	-	.170	-	4
е	2.29	BSC	.090	BSC	
L	8.89	9.65	.350	.380	
L1	1.91	2.29	.045	.090	
L2	0.89	1.27	.035	,050	4
L3	1,14	1.52	.045	,060	5
ø1	0.	15'	0*	15"	
ø2	25'	35*	25'	35'	

LEAD ASSIGNMENTS

HEXFET 1.- GATE 2.- DRAIN 3.- SOURCE 4.- DRAIN

I-Pak Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/ www.irf.com

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#### D-Pak (TO-252AA) Tape & Reel Information

Dimensions are shown in millimeters (inches)



#### NOTES :

- 1. CONTROLLING DIMENSION : MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS ( INCHES ).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



NOTES : 1. OUTLINE CONFORMS TO EIA-481.

#### Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature. (See fig. 11).
- ② Limited by T<sub>Jmax</sub>, starting T<sub>J</sub> = 25°C, L = 0.18mH R<sub>G</sub> = 25Ω, I<sub>AS</sub> = 18A, V<sub>GS</sub> =10V. Part not recommended for use above this value.
- 3 Pulse width  $\leq$  1.0ms; duty cycle  $\leq$  2%.
- 4 C<sub>oss</sub> eff. is a fixed capacitance that gives the same charging time as C<sub>oss</sub> while V<sub>DS</sub> is rising from 0 to 80% V<sub>DSS</sub>.
- ⑤ Limited by T<sub>Jmax</sub>, see Fig.12a, 12b, 15, 16 for typical repetitive avalanche performance.
- $\odot$  Limited by T<sub>Jmax</sub>, starting T<sub>J</sub> = 25°C, L = 0.18mH  $\odot$  This value determined from sample failure population,
  - starting  $T_J$  = 25°C, L = 0.18mH,  $R_G$  = 25 $\Omega$ ,  $I_{AS}$  = 18A,  $V_{GS}$  =10V.
  - ⑦ When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.
  - $\$  R<sub>heta</sub> is measured at TJ approximately 90°C.

### **Ordering Information**

Base part	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRFR4105Z	Dpak	Tube	75	AUIRFR4105Z
		Tape and Reel	2000	AUIRFR4105ZTR
		Tape and Reel Left	3000	AUIRFR4105ZTRL
		Tape and Reel Right	3000	AUIRFR4105ZTRR
AUIRFU4105Z	lpak	Tube	75	AUIRFU4105Z

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